Detecting and Estimating Signals in Noisy Cable Structures, I: Neuronal Noise Sources

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In recent theoretical approaches addressing the problem of neural coding, tools from statistical estimation and information theory have been applied to quantify the ability of neurons to transmit information through their spike outputs. These techniques, though fairly general, ignore the specific nature of neuronal processing in terms of its known biophysical properties. However, a systematic study of processing at various stages in a biophysically faithful model of a single neuron can identify the role of each stage in information transfer. Toward this end, we carry out a theoretical analysis of the information loss of a synaptic signal propagating along a linear, one-dimensional, weakly active cable due to neuronal noise sources along the way, using both a signal reconstruction and a signal detection paradigm.

Here we begin such an analysis by quantitatively characterizing three sources of membrane noise: (1) thermal noise due to the passive membrane resistance, (2) noise due to stochastic openings and closings of voltage-gated membrane channels (Na$^+$ and K$^+$), and (3) noise due to random, background synaptic activity. Using analytical expressions for the power spectral densities of these noise sources, we compare their magnitudes in the case of a patch of membrane from a cortical pyramidal cell and explore their dependence on different biophysical parameters.

1 Introduction

A great deal of effort in cellular biophysics and neurophysiology has concentrated on characterizing nerve cells as input-output devices. A host of experimental techniques like voltage clamp, current clamp, whole-cell recordings, and so on have been used to study how neurons transform their synaptic inputs (in the form of conductance changes) to their outputs (usually in the form of a train of action potentials). It has been firmly established that neurons are highly sophisticated entities, potentially capable of implementing a rich panoply of powerful nonlinear computational primitives (Koch, 1999).
A systematic investigation of the efficacy of neurons as communication devices dates back to well over 40 years ago (MacKay & McCulloch, 1952). More recently, tools from statistical estimation and information theory have been used (Rieke, Warland, van Steveninck, & Bialek, 1997) to quantify the ability of neurons to transmit information about random inputs through their spike outputs. Bialek, Rieke, van Steveninck, & Warland (1991) and Bialek and Rieke (1992) pioneered the use of the reconstruction technique toward this end, based on Wiener’s (1949) earlier work. These techniques have successfully been applied to understand the nature of neural codes in peripheral sensory neurons in various biological neural systems (Rieke et al., 1997). Theoretical investigations into this problem since have given rise to better methods of assessing capacity of neural codes (Strong, Koberle, van Steveninck, & Bialek, 1998; Gabbiani, 1996; Theunissen & Miller, 1991).

In all the above approaches, the nervous system is treated like a black box and is characterized empirically by the collection of its input-output records. The techniques employed are fairly general and consequently ignore the specific nature of information processing in neurons. Much is known about how signals are transformed and processed at various stages in a neuron (Koch, 1999), and a systematic study of neuronal information processing should be able to identify the role of each stage in information transfer. One way to address this question is to pursue a reductionist approach and apply the above tools to the individual components of a neuronal link. This allows us to assess the role of different neuronal subcomponents (the synapse, the dendritic tree, the soma, the spike initiation zone, and the axon) in information transfer from one neuron to another.

We can address critical questions such as which stage represents a bottleneck in information transfer, whether the different stages are matched to each other in order to maximize the amount of information transmitted, how neuronal information processing depends on the different biophysical parameters that characterize neuronal hardware, and so on. The rewards from such a biophysical approach to studying neural coding are multifarious. However, first we need to characterize the different noise sources that cause information loss at each stage in neuronal processing. For the purposes of this article (and its sequel which follows in this issue), we focus on linear one-dimensional dendritic cables. An analysis of the information capacity of a simple model of a cortical synapse illustrating the generality our approach has already been reported (Manwani & Koch, 1998).

Here we begin such a theoretical analysis of the information loss that a signal experiences as it propagates along a one-dimensional cable structure due to different types of distributed neuronal noise sources (as discussed extensively in DeFelice, 1981). We consider two paradigms: signal detection in which the presence or absence of a signal is to be detected, and signal estimation in which an applied signal needs to be reconstructed. This calculus can be regarded as a model for electrotonic propagation of synaptic signals to the soma along a linear yet weakly active dendrite.
For real neurons, propagation is never entirely linear; the well-documented presence of voltage-dependent membrane conductance in the dendritic tree can dramatically influence dendritic integration and propagation of information. Depending on their relative densities, the presence of different dendritic ion channel species can lead to both nonlinear amplification of synaptic signals, combating the loss due to electrotonic attenuation (Bernander, Koch, & Douglas, 1994; Stuart & Sakmann, 1994, 1995; Cook & Johnston, 1997; Schwindt & Crill, 1995; Magee, Hoffman, Colbert, & Johnston, 1998) and a decrease in dendritic excitability or attenuation of synaptic signals (Hoffman, Magee, Colbert, & Johnston, 1997; Magee et al., 1998; Stuart & Spruston, 1998).

The work discussed here is restricted to linear cables (passive or quasi-active Koch, 1984; that is, the membrane can contain inductive-like components) and can be regarded as a first-order approximation, which is amenable to closed-form analysis. Biophysically more faithful scenarios that consider the effect of strong, active nonlinear membrane conductances can be analyzed only via numerical simulations that will be reported in the future.

Our efforts to date can be conveniently divided into two parts. In the first part, described in this article, we characterize three sources of noise that arise in nerve membranes: (1) thermal noise due to membrane resistance (Johnson noise), (2) noise due to the stochastic channel openings and closings of two voltage-gated membrane channels, and (3) noise due to random background synaptic activity. Using analytical expressions for the power spectral densities of these noise sources, we compute their magnitudes for biophysically plausible parameter values obtained from different neuronal models in the literature.

In a second step, reported in a companion article, we carry out a theoretical analysis of the information loss of a synaptic signal as it propagates to the soma, due to the presence of these noise sources along the dendrite. We model the dendrite as a weakly active linear cable with noise sources distributed all along its length and derive expressions for the capacity of this dendritic channel under the signal detection and estimation paradigms. We are now also engaged in carrying out quantitative comparison of these noise estimates against experimental data (Manwani, Segev, Yarom, & Koch, 1998). A list of symbols used in this article and the following one is in the appendix.

2 Sources of Neuronal Noise

In general, currents flowing through ion-specific membrane proteins (channels) depend nonlinearly on the voltage difference across the membrane (Johnston & Wu, 1995),

\[ i = f(V_m) \]  

(2.1)
where $i$ represents the ionic current through the channel and $V_m$ is the membrane voltage. Often the current satisfies Ohm’s law (Hille, 1992); $i$ can be expressed as the product of the driving potential across the channel $V_m - E_{ch}$ and the voltage- (or ligand concentration) dependent channel conductance $g_{ch}$ as,

$$i = g_{ch}(V_m)(V_m - E_{ch}),$$

(2.2)

where $E_{ch}$ (the membrane voltage for which $i = 0$) is the reversal potential of the channel.

If $i$ is small enough so that the flow of ions across the membrane does not significantly change $V_m$, the change in ionic concentrations is negligible ($E_{ch}$ does not change), and so the driving potential is almost constant and $i \propto g_{ch}$. Thus, for a small conductance change, the channel current is approximately independent of $V_m$ and is roughly proportional to the conductance change. Thus, although neuronal inputs are usually in terms of conductance changes, currents can equivalently be regarded as the inputs for small inputs. This argument holds for both ligand-gated and voltage-gated channels. We shall use this assumption throughout this article and regard currents, and not conductances, as the input variables.

The neuron receives synaptic signals at numerous locations along its dendritic tree. These current inputs are integrated by the tree and propagate as voltages toward the soma and the axon hillock, close to the site where the action potentials are generated. Thus, if we restrict ourselves to the study of the information loss due to the dendritic processing that precedes spike generation, currents are the input variables, and the membrane voltage at the spike initiating zone can be considered to be the output variable.

We first consider some of the current noise sources present in nerve membranes that distort the synaptic signal as it propagates along the cable. As excellent background source text on noise in neurobiological systems, we recommend DeFelice (1981).

### 2.1 Thermal Noise.

Electrical conductors are sources of thermal noise resulting from random thermal agitation of the electrical charges in the conductor. Thermal noise, also known as Johnson noise, represents a fundamental lower limit of noise in a system and can be reduced only by decreasing the temperature or the bandwidth of the system (Johnson, 1928). Thermal noise is also called white noise because its power spectral density is flat for all frequencies, except when quantum effects come into play. Since thermal noise results from a large ensemble of independent sources, its amplitude distribution is gaussian as dictated by the central limit theorem (Papoulis, 1991). The power spectral density of the voltage fluctuations due to thermal noise (denoted by $S_{Vth}$) in a conductor of resistance $R$ in equilibrium (no current flowing through the conductor) is given by,

$$S_{Vth}(f) = 2kTR \text{ (units of V}^2\text{/Hz)},$$

(2.3)
where $k$ denotes the Boltzmann constant and $T$ is the absolute temperature of the conductor. Consequently, the variance of the voltage fluctuations due to thermal noise, $\sigma^2_{V_{th}}$, is

$$\sigma^2_{V_{th}} = \int_{-B}^{B} S_{V_{th}}(f) \, df = 4kTRB \text{ (units of } V^2).$$

(2.4)

where $B$ denotes the bandwidth of the measurement system.$^1$

Thus, a conductor of resistance $R$ can be replaced by an ideal noiseless resistor $R$ in series with a voltage noise source $V_{th}(t)$, which has a power spectral density given by $S_{V_{th}}(f)$ (see Figure 1A). Equivalently, one can replace the conductor with a noiseless resistor $R$ in parallel with a current noise source $I_{th}(t)$ with power spectral density denoted by $S_{I_{th}}(f)$ (see Figure 1B) given by the expression,

$$S_{I_{th}}(f) = \frac{2kT}{R} \text{ (units of } A^2/\text{Hz}).$$

(2.5)

$^1$ All power spectral densities are assumed to be double-sided, since the power spectra of real signals are even functions of frequency.
Figure 2: Ladder network model of an infinite linear cable. $r_i$ represents the longitudinal (axial) resistance due to the cytoplasm, whereas $r_m$ and $c_m$ denote the transverse membrane resistance and capacitance, respectively. $c_i$ denotes the (usually negligible) axial capacitance (dotted lines), which ensures that the thermal noise has a bounded variance.

Since we assume the inputs to be currents, we shall use the latter representation. A passive one-dimensional cable can be modeled as a distributed network of resistances and capacitances, as shown in Figure 2. $r_m$ and $c_m$ denote the resistance and the capacitance across the membrane (transversely), respectively. $r_i$ represents the resistance (longitudinal) of the intracellular cytoplasm. $c_m$ arises due to the capacitance of the thin, insulating, phospholipid bilayer membrane, which separates the intracellular cytoplasm and external solution. In general, excitable membrane structures containing active voltage- and time-dependent conductances cannot be modeled as ladder networks comprising resistances and capacitances alone, even if they behave linearly over a given voltage range. The time-dependent nature of voltage-gated channel conductances gives rise to phenomenological inductances (Sabah & Leibovic, 1969, 1972; Mauro, Conti, Dodge, & Schor, 1970; Mauro, Freeman, Cooley, & Cass, 1972; Koch, 1984). Thus, in general, the small-signal circuit equivalent of an active, linearized membrane is a resistor-inductor-capacitor (RLC) circuit consisting of resistances, capacitances, and inductances. For an illustration of this linearization procedure, refer to the independent appendix (Small Signal Impedance of Active Membranes) available over the Internet\(^2\) or to Chapter 10 in Koch (1999).

However, when the time constants corresponding to the ionic currents are much faster than the passive membrane time constant, the phenomenological inductances are negligible and the equivalent circuit reduces to the passive ladder model for the cable. This is true for the case we consider; the passive membrane time constant is about an order of magnitude greater than the slowest timescale of the noise sources, and so the approximation above is a reasonable one. $r_m$ reflects the effective resistance of the lipid

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\(^2\) Please download the postscript or pdf files from http://www.klab.caltech.edu/~quixote/publications.html.
bilateral (very high resistance) and the various voltage-gated, ligand-gated, and leak channels embedded in the lipid matrix. Here we ignore the external resistance, \( r_e \), of the external medium surrounding the membrane. All quantities \( (r_i, r_m, c_m) \) are expressed in per unit length of the membrane and have the dimensions of \( \Omega/\mu m, \mu m, \) and \( F/\mu m \), respectively. For a linear cable, modeled as a cylinder of diameter \( d \), \( r_m = R_m / \pi d, c_m = \pi d C_m \), 
\[ r_i = 4R_i / \pi d^2 \] where \( R_m, C_m, \) and \( R_i \) (specific membrane resistance, specific membrane capacitance, and axial resistivity, respectively) are the usual biophysical parameters of choice.

The current noise due to \( r_m \), has power spectral density,

\[ S_{Vth}(f) = \frac{2kT}{r_m} \] (units of \( A^2/Hz \)). (2.6)

However, \( r_m \) is not the only source of thermal noise. The resistance \( r_i \), representing the axial cytoplasmic resistance, also contributes thermal noise. In general, the power spectral density of the voltage noise due to thermal fluctuations in an impedance \( Z \) is given by

\[ S_{Vth}(f) = 2kT \text{Re}(Z(f)), \] (2.7)

where \( \text{Re}(Z(f)) \) is the real part of the impedance as a function of frequency. Thus, the voltage variance is given by

\[ \sigma_{Vth}^2 = \int_{-\infty}^{\infty} S_{Vth}(f) \, df \] (units of \( V^2 \)). (2.8)

For a semi-infinite passive cable (see Figure 2), the input impedance is given as

\[ Z(f) = \frac{\sqrt{r_mm}}{\sqrt{1 + \left[2\pi f r_mm\right]^2}} \] (2.9)

\[ \Rightarrow \text{Re}(Z(f)) = \frac{\sqrt{r_mm}}{\sqrt{1 + (2\pi f r_mm)^2}} \cos \left( \frac{\tan^{-1} 2\pi f r_mm}{2} \right). \] (2.10)

which yields

\[ S_{Vth}(f) = \frac{2kT \sqrt{r_mm}}{\left[1 + (2\pi f r_mm)^2\right]^{1/4}} \cos \left( \frac{\tan^{-1} 2\pi f r_mm}{2} \right). \] (2.11)

The integral of \( S_{Vth}(f) \) in equation 2.11 is divergent, and so \( \sigma_{Vth}^2 \) is infinite. This can be seen easily by rewriting the expression for \( S_{Vth} \) as

\[ S_{Vth}(f) = \sqrt{2r_mm kT} \left[ \frac{1}{1 + (2\pi f r_mm)^2} + \frac{1}{\sqrt{1 + (2\pi f r_mm)^2}} \right]^{1/2}. \] (2.12)
In the limit of large $f$, $S_{Vih}(f) \sim f^{-1/2}$, the indefinite integral of which diverges. This divergence is due not to $r_m$ but due to $r_i$. The noise due to $r_m$ alone is of finite variance since the cable introduces a finite bandwidth. The resolution of this nonphysical phenomenon lies in realizing that a pure resistance is a nonphysical idealization. The cytoplasm is associated with a longitudinal capacitance in addition to its axial resistance, since current flow through the cytoplasm does not occur instantaneously. Ionic mobility is much smaller than that of electrons, and charge accumulation takes place along the cytoplasm as a consequence. This can be modeled by the addition of an effective capacitance, $c_i$ (the dotted lines in Figure 2) in parallel with $r_i$. Now, $S_{Vih}(f)$ is given by

\[
S_{Vih}(f) = \frac{2kT\sqrt{r_i/\tau_m}}{[(1 + \theta_1^2) (1 + \theta_2^2)]^{1/4}} \cos \left(\frac{\tan^{-1} \theta_1 + \tan^{-1} \theta_2}{2}\right),
\]

where

\[
\theta_1 = 2\pi f \tau_m \quad \text{and} \quad \theta_2 = 2\pi f \tau_i,
\]

where $\tau_i$ is the time constant of the axial RC segment. $\tau_i$ is usually very low, on the order of $3\mu\text{sec}$ (Rosenfalck, 1969). In this case, for large $f$, $S_{Vih}(f) \sim f^{-2}$; thus its integral converges, and $\sigma_{Vih}^2$ remains finite.

The additional filtering due to the cytoplasmic capacitances imposes a finite bandwidth on the system, rendering the variance finite. Since $\tau_i \ll \tau_m$, its effect is significant only at very large frequencies, as shown in Figure 3. Thus, neglecting the noise due to the cytoplasmic resistance is a reasonable approximation for our frequency range of interest (1–1000 Hz).

### 2.2 Channel Noise.

The membrane conductances we consider here are a consequence of microscopic, stochastic ionic channels (Hille, 1992). Since these channels open and close randomly, fluctuations in the number of channels constitute a possible source of noise. In this section, we restrict the discussion to voltage-gated channels. However, ligand-gated channels can also be analyzed using the techniques discussed here. In a detailed appendix, available over the Web (http://www.klab.caltech.edu/~quixote/publications.html), we present an analysis of the noise due to channel fluctuations for a simple two-state channel model for completeness. We apply well-known results from the theory of Markov processes, reviewed in DeFelice (1981) and Johnston and Wu, (1995), to Hodgkin-Huxley-like models of voltage-gated $K^+$ and $Na^+$ channels. It is straightforward to extend these results to other discrete state channel models.

#### 2.2.1 $K^+$ Channel Noise.

The seminal work by Hodgkin and Huxley (1952) represents the first successful attempt at explaining the nature of membrane excitability in terms of voltage-gated particles. Most of our un-
Figure 3: Thermal noise models for a semi-infinite cable. Comparison of power spectral densities of thermal voltage noise in an infinite cable corresponding to different assumptions. When the contribution due to the cytoplasmic resistance $r_i$ is neglected (labeled as $r_m, c_m$), $S_{V_{th}}(f)$ represents the current noise due to the transmembrane resistance $r_m$ filtered by the Green’s function of the infinite cable. $S_{V_{th}}(f) \sim f^{-3/2}$ for large $f$. When noise due to $r_i$ is included (labeled as $r_m, c_m, r_i$) and equation 2.11 is used, $S_{V_{th}}(f) \sim f^{-1/2}$ and so the variance is infinite. When filtering due to an effective cytoplasmic capacitance $c_i$ is taken into account (labeled as $r_m, c_m, r_i, c_i$) and equation 2.13 is used, for which $S_{V_{th}}(f) \sim f^{-2}$. The integral of this power spectrum is bounded, and so the variance remains finite. Parameter values: $R_m = 40,000 \, \Omega/cm^2$, $R_i = 200 \, \Omega/cm$, $\tau_m = 30 \, msec$, $\tau_i = 3 \, \mu\text{sec}$.

Understanding of membrane channels has been directly or indirectly influenced by their ideas (Hille, 1992).

In the Hodgkin-Huxley formulation, a K$^+$ channel consists of four identical two-state subunits. The K$^+$ channel conducts only when all the subunits are in their open states. Each subunit can be regarded as a two-state binary switch (like the model above) where the rate constants ($\alpha$ and $\beta$) depend on $V_m$. Hodgkin and Huxley used data from voltage-clamp experiments on the giant squid axon to obtain empirical expressions for this voltage dependence. Since the subunits are identical, the channel can be in one of five states, from the state corresponding to all subunits closed to the open state...
in which all subunits are open. In general, a channel composed of \( n \) subunits has \( n \) distinct states if all the subunits are identical and \( 2^n \) states if all the subunits are distinct. The simplest kinetic scheme corresponding to a K\(^+\) channel can be written as

\[
\begin{align*}
C_0 & \quad \frac{4a_n}{\beta_n} \\
C_1 & \quad \frac{3a_n}{2\beta_n} \\
C_2 & \quad \frac{2a_n}{3\beta_n} \\
C_3 & \quad \frac{a_n}{4\beta_n} \\
O & \quad 1
\end{align*}
\]

(1)

where \( C_i \) denotes the state in which \( i \) subunits are open and \( O \) is the open state with all subunits open. Thus, the evolution of a single K\(^+\) channel can be regarded as a five-state Markov process with the following state transition matrix:

\[
\mathbf{Q}_K = \begin{bmatrix}
-4\alpha_n & 4\alpha_n & 0 & 0 & 0 \\
\beta_n & -3(\alpha_n + \beta_n) & 3\alpha_n & 0 & 0 \\
0 & 2\beta_n & -(2\alpha_n + 2\beta_n) & 2\alpha_n & 0 \\
0 & 0 & 3\beta_n & -(\alpha_n + 3\beta_n) & \alpha_n \\
0 & 0 & 0 & 4\beta_n & -4\beta_n
\end{bmatrix}
\]

\( \mathbf{Q}_K \) is a singular matrix with four nonzero eigenvalues that correspond to the cutoff frequencies in the K\(^+\) current noise spectrum. If the probability of a subunit’s being open is denoted by \( n(t) \), the open probability of a single K\(^+\) channel, \( p_K \), is equal to \( n(t)^4 \). At steady state, the probability of a subunit’s being open at time \( t \) given that it was open at \( t = 0 \) (\( \Pi_{55}(t) \) according to our convention) is given by

\[
\Pi_{55}(t) = n_\infty + (1 - n_\infty)e^{-|t|/\theta_n},
\]

(2.14)

where

\[
n_\infty = \frac{a_n}{\alpha_n + \beta_n} \quad \text{and} \quad \theta_n = \frac{1}{\alpha_n + \beta_n}
\]

(2.15)

denote the steady-state open probability and relaxation time constant of the \( n \) subunit, respectively. Thus, the autocovariance of the current fluctuations due to the random opening and closing of K\(^+\) channels in the nerve membrane can be written by analogy,

\[
C_{IK}(\tau) = \eta_K y_K^2 (V_m - E_K)^2 \left[ \Pi_{55}(\tau)^4 n_\infty^4 - n_\infty^8 \right]
\]

(2.16)

\[
= \eta_K y_K^2 (V_m - E_K)^2 \left[ n_\infty^4 (n_\infty + (1 - n_\infty)e^{-|\tau|/\theta_n})^4 - n_\infty^8 \right].
\]

(2.17)

where \( \eta_K, y_K, \) and \( E_K \) denote the K\(^+\) channel density in the membrane, the open conductance of a single K\(^+\) channel, and the potassium reversal potential, respectively. On expansion we obtain,

\[
C_{IK}(\tau) = \eta_K y_K^2 (V_m - E_K)^2 n_\infty^4 \sum_{i=1}^4 \left( \begin{array}{l} 4 \\ i \end{array} \right) (1 - n_\infty)^i n_\infty^4 e^{-|\tau|/\theta_n},
\]

(2.18)
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where

\[
\binom{n}{i} = \frac{n!}{(n-i)!i!}.
\]

The variance of the K\textsuperscript{+} current, \(\sigma_{IK}^2 = C_{IK}(0)\), is

\[
\sigma_{IK}^2 = \eta_K Y_K^2 (V_m - E_K)^2 n_\infty^4 (1 - n_\infty^4)
\]

\[
= \eta_K Y_K^2 (V_m - E_K)^2 p_K (1 - p_K).
\]

Taking the Fourier transform of \(C_{IK}(\tau)\) gives us the power spectrum of the K\textsuperscript{+} current noise, \(S_{IK}(f)\),

\[
S_{IK}(f) = \eta_K Y_K^2 (V_m - E_K)^2 n_\infty^4 \sum_{i=1}^{4} \binom{4}{i} (1 - n_\infty^4)^{i-1} - \frac{2\theta_n/i}{1 + (2\pi f/\theta_n)^2}.
\]

Notice that \(S_{IK}(f)\) is given by a sum of four Lorentzian functions with different amplitude and cutoff frequencies. For \(n_\infty \ll 1\), one can obtain a useful approximation for \(S_{IK}(f)\),

\[
S_{IK}(f) \approx \eta_K Y_K^2 (V_m - E_K)^2 n_\infty^4 (1 - n_\infty^4)^4 \frac{2\theta_n/4}{1 + (2\pi f/\theta_n/4)^2}
\]

\[
\approx \frac{S_{IK}(0)}{1 + (f/f_K)^2} \quad \text{(units of A}^2/\text{Hz)},
\]

where

\[
S_{IK}(0) = \frac{\eta_K}{2} Y_K^2 (V_m - E_K)^2 n_\infty^4 (1 - n_\infty^4)^4 \theta_n \quad \text{and} \quad f_K = \frac{4}{2\pi \theta_n}.
\]

For small values of \(n_\infty\), the transitions \(O \rightarrow C_3\) and \(C_0 \rightarrow C_1\) dominate and the power spectrum can be approximated by a single Lorentzian with amplitude \(S_{IK}(0)\) and cutoff frequency \(f_K\). In this case the bandwidth\(^3\) of K\textsuperscript{+} current noise is given by \(B_K \approx 1/\theta_n\). This approximation holds when the membrane voltage \(V_m\) is close to its resting potential \(V_{rest}\).

2.2.2 Na\textsuperscript{+} Channel Noise. The Hodgkin-Huxley Na\textsuperscript{+} current is characterized by three identical activation subunits denoted by \(m\) and an inactivation subunit denoted by \(h\). The Na\textsuperscript{+} channel conducts only when all the \(m\) subunits are open and the \(h\) subunit is not inactivated. Each of the subunits may flip between their open (respectively, not inactivated) and closed

\(^3\) Defined as \(B_K = \sigma_{IK}^2 / 2 S_{IK}(0)\), the variance divided by the twice the magnitude of the power spectrum.
respectively, inactivated) states with the voltage-dependent rate constants $\alpha_m$ and $\beta_m$ (respectively, $\alpha_h$ and $\beta_h$) for the $m$ (respectively, $h$) subunit. Thus, the Na$^+$ channel can be in one of eight states from the state corresponding to all $m$ subunits closed and the $h$ subunit inactivated to the open state with all $m$ subunits open and the $h$ subunit not inactivated:

\[
\begin{align*}
&1/2/3/4/C_0^3fi_m^>fl_m \quad 1/2/3/4/C_1^2fi_m^>2fl_m \quad 1/2/3/4/C_2^1fi_m^>3fl_m \quad 1/2/3/4/O^0fi_m^>4fl_m \\
&I_0^3fi_h^>fl_h \quad I_1^2fi_h^>2fl_h \quad I_2^1fi_h^>3fl_h \quad I_3^0fi_h^>4fl_h
\end{align*}
\]

where $C_i$ (respectively, $I_i$) denotes the state corresponding to $i$ open subunits of the $m$ type and the $h$ subunit is not inactivated (respectively inactivated). The state transition matrix is given by

\[
Q_{Na} = \begin{bmatrix}
-3\alpha_m + \beta_h & 3\alpha_m & 0 & 0 & 0 & 0 & 0 & 0 \\
\beta_m - (2\alpha_m + \beta_h) & 2\alpha_m & 0 & 0 & \beta_h & 0 & 0 & 0 \\
0 & -2\beta_m & \alpha_h (2\beta_m + \alpha_m + \beta_h) & \alpha_m & 0 & 0 & \beta_h & 0 \\
0 & 3\beta_m & -3\beta_m + \alpha_m & 0 & 0 & 0 & \beta_h & 0 \\
\alpha_m & 0 & 0 & 0 & -3\alpha_m + \alpha_h & 3\alpha_m & 0 & 0 \\
0 & \alpha_h & 0 & 0 & \beta_m - (2\alpha_m + \beta_h) & 2\alpha_m & 0 & 0 \\
0 & 0 & \alpha_h & 0 & 0 & 2\beta_m & -\alpha_m (2\beta_m + \alpha_h) & \alpha_m \\
0 & 0 & 0 & \alpha_h & 0 & 0 & 3\beta_m & -3\beta_m + \alpha_h
\end{bmatrix}
\]

$Q_{Na}$ has seven nonzero eigenvalues, and so the Na$^+$ channel has seven time constants. Thus, the Na$^+$ current noise spectrum can be expressed as a sum of seven Lorentzians with cutoff frequencies corresponding to these time constants. The autocovariance of the current fluctuations due to the sodium channels is given as

\[
C_{INa}(\tau) = \eta_{Na} \gamma_{Na}^2 (V_m - E_{Na})^2 \left[ m_\infty^3 h_\infty^2 \left( m_\infty + (1 - m_\infty) e^{-|\tau|/\theta_m} \right)^3 \right] \\
\left[ h_\infty + (1 - h_\infty) e^{-|\tau|/\theta_h} \right] - m_\infty^6 h_\infty^2, \quad (2.25)
\]

where $\eta_{Na}$, $\gamma_{Na}$ and $E_{Na}$ denote the Na$^+$ channel density, the Na$^+$ single channel conductance, and the sodium reversal potential, respectively.

\[
m_\infty = \frac{\alpha_m}{\alpha_m + \beta_m}, \quad \theta_m = \frac{1}{\alpha_m + \beta_m} \quad (2.26)
\]

\[
h_\infty = \frac{\alpha_h}{\alpha_h + \beta_h}, \quad \theta_h = \frac{1}{\alpha_h + \beta_h} \quad (2.27)
\]

denote the corresponding steady-state values and time constants of the $m$
and $h$ subunits. The variance can be written as

$$
\sigma_{\text{INa}}^2 = \eta_{\text{Na}} \gamma_{\text{Na}}^2 (V_m - E_{\text{Na}})^2 m_{\infty}^2 h_{\infty} (1 - m_{\infty}^3 h_{\infty})
$$

(2.28)

$$
\sigma_{\text{INa}}^2 = \eta_{\text{Na}} \gamma_{\text{Na}}^2 (V_m - E_{\text{Na}})^2 p_{\text{Na}} (1 - p_{\text{Na}}).
$$

(2.29)

where $p_{\text{Na}} = m_{\infty}^3 h_{\infty}$ is the steady-state open probability of a Na$^+$ channel.

The power spectrum, obtained by taking the Fourier transform of $C_{\text{INa}}(\tau)$, is given by a combination of seven Lorentzian components. The general expression is tedious and lengthy to express, and so we shall restrict ourselves to a reasonable approximation. For $m_{\infty} \ll 1$ and $h_{\infty} \approx 1$, around the resting potential.

$$
S_{\text{INa}}(f) \approx \frac{2 \theta_m / 3}{1 + (f/f_{\text{Na}})^2}
$$

(2.30)

$$
S_{\text{INa}}(0) = \frac{2 \eta_{\text{Na}} \gamma_{\text{Na}}^2 (V_m - E_{\text{Na}})^2 m_{\infty}^3 h_{\infty} (1 - m_{\infty})^3 h_{\infty} \theta_m}{3}
$$

(2.31)

where

$$
f_{\text{Na}} = \frac{3}{2 \pi \theta_m}.
$$

(2.32)

Thus, for voltages close to the resting potential, $S_{\text{INa}}(f)$ can be approximated by a single Lorentzian. The bandwidth of Na$^+$ current noise under this approximation is given by $B_{\text{Na}} \approx 3/4 \theta_m$.

In general, the magnitude and shape of the power spectrum are determined by the kinetics of corresponding single channels. For any given state transition matrix describing the channel kinetics, we can derive expressions for the noise power spectral densities using the procedure outlined above. For most kinetic models, when $V_m \approx V_{\text{rest}}$, the single Lorentzian approximation suffices. A variety of kinetic schemes modeling different types of voltage-gated ion channels exist in the literature. We shall choose a particular scheme to work with, but the formalism is very general and can be used to study arbitrary finite-state channels.

### 2.3 Synaptic Noise

In addition to voltage-gated channels that open and close in response to membrane potential changes, dendrites (and the associated spines, if any) are also awash in ligand-gated synaptic receptors. We shall restrict our attention to the family of channels specialized for mediating fast chemical synaptic transmission in a voltage-independent manner, excluding for now NMDA-type of currents.
Chemical synaptic transmission is usually understood as a conductance change in the postsynaptic membrane caused by the release of neurotransmitter molecules from the presynaptic neuron in response to presynaptic membrane depolarization. A commonly used function to represent the time course of the postsynaptic change in response to a presynaptic spike is the alpha function (Rall, 1967; Koch, 1999),

$$g_\alpha(t) = g_{\text{peak}} \frac{t}{t_{\text{peak}}} e^{1-t/t_{\text{peak}}} u(t),$$

(2.33)

where $g_{\text{peak}}$ denotes the peak conductance change and $t_{\text{peak}}$ is the time to peak of the conductance change. $u(t)$ is the unit step function that ensures that $g_\alpha(t) = 0$ for $t < 0$. More general kinetic descriptions have been proposed to model synaptic transmission (Destexhe, Mainen, & Sejnowski, 1994) but are not considered here.

We shall assume that for a spike train $s(t) = \sum \delta(t - t_j)$, modeled as a sum of impulses occurring at times $t_j$, the postsynaptic change is given by a sum of time-shifted conductance functions,

$$g_{\text{Syn}}(t) = \sum_j g_\alpha(t - t_j).$$

(2.34)

This means that each spike causes the same conductance change and that the conductance change due to a sequence of spikes is the sum of the changes due to individual spikes in the train. For now, we ignore the effect of paired-pulse facilitation or depression (Abbott, Varela, Sen, & Nelson, 1997; Tsodyks & Markram, 1997). The synaptic current $i_{\text{Syn}}(t)$ is given by

$$i_{\text{Syn}}(t) = g_{\text{Syn}}(t) (V_m - E_{\text{Syn}}),$$

(2.35)

where $E_{\text{Syn}}$ is the synaptic reversal potential. As before, we assume that the synaptic current is small enough so that $V_m$ is nearly constant. If the spike train of the presynaptic neuron can be modeled as a homogeneous Poisson process with mean firing rate $\lambda_n$, one can compute the mean and variance of the synaptic current arriving at the membrane using Campbell’s theorem (Papoulis, 1991):

$$\langle i_{\text{Syn}}(t) \rangle = \lambda_n (V_m - E_{\text{Syn}}) \int_0^\infty g_\alpha(t) \, dt;$$

(2.36)

$$\sigma_{\text{Syn}}^2 = \lambda_n (V_m - E_{\text{Syn}})^2 \int_0^\infty (g_\alpha(t))^2 \, dt.$$  

(2.37)

It is straightforward to compute the autocovariance $C_{i_{\text{Syn}}}(\tau)$ of the synaptic current,

$$C_{i_{\text{Syn}}}(\tau) = \lambda_n (V_m - E_{\text{Syn}})^2 \int_0^\infty g_\alpha(t) * g_\alpha(-t) \, dt;$$

(2.38)

$$= \lambda_n (V_m - E_{\text{Syn}})^2 \int_0^{\infty} g_\alpha(t) g_\alpha(t + \tau) \, dt.$$  

(2.39)
Similarly, the power spectral density of the synaptic current is given by

\[ S_{ISyn}(f) = |\mathcal{F}\{C_{ISyn}(\tau)\}|^2 = \lambda_n (V_m - E_{Syn})^2 |G_a(f)|^2, \]  

(2.40)

where

\[ G_a(f) = \mathcal{F}\{g_a(t)\} = \int_0^\infty g_a(t) e^{-j2\pi ft} dt \]  

(2.41)

denotes the Fourier transform of \( g_a(t) \). For the alpha function,

\[ G_a(f) = \frac{e^{g_{peak} t_{peak}}}{(1 + j2\pi ft_{peak})^2}. \]  

(2.42)

It has been shown that if the density of synaptic innervation is high or, alternatively, if the firing rates of the presynaptic neurons are high and the conductance change due to a single impulse is small, the synaptic current tends to a gaussian process (Tuckwell & Wan, 1980). This is called the diffusion approximation. Since a gaussian process is completely specified by its power spectral density, one only needs to compute the power spectrum of current noise due to random synaptic activity. If \( \eta_{Syn} \) denotes the synaptic density, the variance, autocovariance, and power spectral density of the synaptic current noise are given by

\[ \sigma_{ISyn}^2 = \eta_{Syn} \lambda_n \left( \frac{g_{peak} e}{2} \right)^2 (V_m - E_{Syn})^2 t_{peak}, \]  

(2.43)

\[ C_{ISyn}(\tau) = \sigma_{ISyn}^2 \left[ 1 + |\tau|/\tau_{peak} \right] e^{-|\tau|/t_{peak}}, \]  

(2.44)

\[ S_{ISyn}(f) = \eta_{Syn} \lambda_n \left[ e^{g_{peak} t_{peak}} (V_m - E_{Syn})^2 \right]^2 \left[ 1 + (2\pi f t_{peak})^2 \right], \]  

(2.45)

\[ = \frac{S_{ISyn}(0)}{[1 + (f/f_{Syn})^2]^2} \text{ (units of } A^2/\text{Hz}), \]  

(2.46)

where

\[ S_{ISyn}(0) = 4 \sigma_{ISyn}^2 t_{peak} \text{ and } f_{Syn} = \frac{1}{2\pi t_{peak}}. \]  

(2.47)

A power spectrum of the above form is called a double Lorentzian spectrum. As before, the power spectrum can be represented in terms of its dc amplitude \( S_{ISyn}(0) \) and its cutoff frequency \( f_{Syn} \). The double Lorentzian spectrum falls twice as fast with the logarithm of frequency as compared to a single Lorentzian because of the double pole at \( f_{Syn} \). Thus, \( f_{Syn} \) is the frequency for which the magnitude of the power spectrum is one-fourth of its amplitude. Using our definition of bandwidth, the bandwidth of the synaptic current noise, \( B_{Syn} = \frac{\pi}{4} f_{Syn} = 1/8 t_{peak} \).
Table 1: Summary of Expressions Used to Characterize Current Noise Due to Conductance Fluctuations (K⁺, Na⁺) and Random Synaptic Activity.

<table>
<thead>
<tr>
<th>Noise Type</th>
<th>K⁺</th>
<th>Na⁺</th>
<th>Synaptic</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\sigma^2_C$</td>
<td>$\eta_k I_{\text{K,max}} pK(1-pK)$</td>
<td>$\eta_{\text{Na}} I_{\text{Na,max}} pNa(1-pNa)$</td>
<td>$(e/2)^2 \eta_{\text{Syn}} \lambda_{\text{Syn}} I_{\text{Syn,max}}$</td>
</tr>
<tr>
<td>$C_i(\tau)/\sigma^2_C$</td>
<td>$\exp(-</td>
<td>\tau</td>
<td>/4 \theta_n)$</td>
</tr>
<tr>
<td>$f_c$</td>
<td>$4/(2\pi \theta_n)$</td>
<td>$3/(2\pi \theta_n)$</td>
<td>$1/(2\pi \tau_{\text{peak}})$</td>
</tr>
<tr>
<td>$S_I(0)$</td>
<td>$\sigma_{\text{K}}^2 \theta_n^2/2$</td>
<td>$2 \sigma_{\text{Na}}^2 \theta_n^2/3$</td>
<td>$4 \sigma_{\text{Syn}}^2 \tau_{\text{peak}}$</td>
</tr>
<tr>
<td>$S_I(f)/S_I(0)$</td>
<td>$1/[1 + (f/f_c)^2]$</td>
<td>$1/[1 + (f/f_{\text{Na}})^2]$</td>
<td>$1/[1 + (f/f_{\text{Syn}})^2]^2$</td>
</tr>
<tr>
<td>$B$</td>
<td>$1/\theta_n$</td>
<td>$3/(4\theta_n)$</td>
<td>$1/(8 \tau_{\text{peak}})$</td>
</tr>
</tbody>
</table>

Notes: For Na⁺ and K⁺ we have made the assumption that the membrane voltage is around the resting value. $I_{\text{K,max}} = \gamma_k(V_m - E_k)$, $I_{\text{Na,max}} = \gamma_{\text{Na}}(V_m - E_{\text{Na}})$ and $I_{\text{Syn,max}} = \gamma_{\text{Syn}}(V_m - E_{\text{Syn}})$ denote the maximum possible values of current through a single K⁺ channel, Na⁺ channel, and synapse, respectively. Since densities are expressed in terms of per unit area, $\sigma^2_C$ and $S_I$ have units of $\text{A}^2/\mu\text{m}^2$ and $\text{A}^2/\text{Hz} \mu\text{m}^2$, respectively.

2.4 Other Sources of Noise. In addition to these sources, there are several other sources of noise in biological membranes (Verveen & DeFelice, 1974; Neher & Stevens, 1977; DeFelice, 1981). The neuronal membrane contains several ionic channels (Hille, 1992) obeying different kinetics. Random fluctuations in the number of these channels also contribute to membrane noise. Additionally, myriad types of ligand-gated channels contribute to the noise level. Using the analysis above, it is clear that if accurate estimates of their relevant parameters (densities, kinetics and so on) are made available, one can potentially compute their contributions to membrane noise as well.

Other types of membrane noise are $1/f$ noise (Neumcke, 1978; Clay & Shlesinger, 1977) (also called excess or flicker noise), shot noise due to ions in transit through leak channels or pores (Frehland & Faulhaber, 1980; Frehland, 1982), carrier-mediated transport noise in ionic pumps, and burst noise. We did not include these in our analysis, either due to a lack of a sound theoretical understanding of their origin or our belief in the relative insignificance of their magnitudes.

A summary of the expressions we have used to characterize the noise sources is provided in Table 1. We have modeled the sources as current fluctuations by assuming that the membrane voltage was clamped at $V_m$. The magnitude and nature of the current fluctuations depend on the kinetics and the driving potential, and thus on $V_m$. In the next section, we investigate the effect of embedding a membrane patch with these noise sources. There we assume that the current fluctuations are small enough so that $V_m$ does not deviate significantly from its resting value, $V_{\text{rest}}$. In general, this approximation must be verified for the different noise sources considered.
We will use the expressions in Table 1 to identify the contribution of each noise source to the total membrane voltage noise for different biophysically relevant parameter values. We will also use these expressions in the following article to quantify the information loss due to these noise sources of a synaptic signal as it propagates down a dendrite.

3 Noise in a Membrane Patch

Consider a patch of neuronal membrane of area $A$, containing Hodgkin-Huxley type rapid sodium $I_{Na}$ and delayed rectifier $I_K$ currents as well as fast voltage-independent synapses. If the patch is small enough, it can be considered as a single point, making the membrane voltage solely a function of time. We shall make this “point-like” assumption here and defer analysis of the general case of spatial dependence of the potential to the following article.

Let $C$ denote the capacitance of the patch, given by the product $C = C_m A$. The passive membrane resistance due to voltage-independent leak channels corresponds to a conductance $g_L$. Current injected into the membrane from all other sources is denoted by $I_{inj}(t)$. Since the area of the patch is known, the absolute values of the conductances can be obtained by multiplying their corresponding specific values by the patch area $A$. On the other hand, if we wish to continue working with specific conductances and capacitances, the injected current needs to be divided by $A$ to obtain the current density. Here we use the former convention. The electric circuit corresponding to a membrane patch is shown in Figure 4. Using Kirchoff's law we have,

$$
C \frac{dV_m}{dt} + g_K(V_m - E_K) + g_{Na}(V_m - E_{Na}) \\
+ g_{Syn}(V_m - E_{Syn}) + g_L(V_m - E_L) = I_{inj}.
$$

(3.1)

Since the ion channels and synapses are stochastic, $g_K$, $g_{Na}$ and $g_{Syn}$ in the above equation are stochastic processes. Consequently, equation 3.1 is in effect a stochastic differential equation. Moreover, since the active conductances ($K^+$, $Na^+$) depend on $V_m$, equation 3.1 is nonlinear in $V_m$ and one has to resort to computationally intensive techniques to study the stochastic dynamics of $V_m(t)$. However, as a consequence of the assumption that the system is in quasi-equilibrium, one can effectively linearize the active conductances around their resting points and express them as deviations around their respective baseline values,

$$
g_K = g_K^0 + \tilde{g}_K,
$$

(3.2)

$$
g_{Na} = g_{Na}^0 + \tilde{g}_{Na},
$$

(3.3)

$$
g_{Syn} = g_{Syn}^0 + \tilde{g}_{Syn},
$$

(3.4)

$$
V_m = V^0 + \nu.
$$

(3.5)
This perturbative approximation can be verified by self-consistency. If the approximation is valid, the deviations of the membrane voltage should be small. For the cases we consider, the membrane fluctuations are small, and so the approximation holds. In general, the validity of this approximation needs to be verified on a case-by-case basis.

\( V^0 \) is chosen such that it satisfies the equation

\[
V^0 = \frac{\mathcal{G}_k E_K + \mathcal{G}_Na E_{Na} + \mathcal{G}_{Syn} E_{Syn} + \mathcal{G}_L E_L}{G},
\]

where \( G = \mathcal{G}_K + \mathcal{G}_{Na} + \mathcal{G}_{Syn} + \mathcal{G}_L \) is the total baseline input conductance of the patch. Similarly, \( \mathcal{G} = \mathcal{G}_K + \mathcal{G}_{Na} + \mathcal{G}_{Syn} \) denotes the total random component of the patch conductance. Substituting for equations 3.2–3.5 in equation 3.1 gives us the following equation,

\[
C \frac{dV_m}{dt} + G(V_m - V^0) + \mathcal{G}_K(V_m - E_K)
\]

\[
+ \mathcal{G}_{Na}(V_m - E_{Na}) + \mathcal{G}_{Syn}(V_m - E_{Syn}) = I_{inj}.
\]

Since the steady-state (resting) solution of equation 3.1 is \( V_m = V_{rest} \), we can choose to linearize about the resting potential, \( V^0 = V_{rest} \). The effective time constant of the patch depends on \( G \) and is given by \( \tau = \frac{C}{G} \). When \( V_m(t) \approx V_{rest} \), \( \mathcal{G}_L \) is usually the dominant conductance, and so \( G \approx \mathcal{G}_L \). However, during periods of intense synaptic activity or for strongly excitable systems, \( G \) can be significantly larger than \( \mathcal{G}_L \) (Bernander, Douglas, Martin, & Koch, 1991; Rapp, Yarom, & Segev, 1992). If no external current is injected, the only other source of current is the thermal current noise, and \( I_{inj} \) is equal to \( I_{th} \).

Expressing \( V_m(t) \) as deviations around \( V_{rest} \) in the form of the variable \( V(t) = V_m(t) - V_{rest} \) allows us to simplify equation 3.7 to

\[
\tau \frac{dV}{dt} + (1 + \delta) V = \frac{I_n}{G},
\]

where

\[
\delta = \frac{\mathcal{G}_K + \mathcal{G}_{Na} + \mathcal{G}_{Syn}}{G} = \frac{\mathcal{G}}{G},
\]

\[
I_n = \mathcal{G}_K(E_K - V_{rest}) + \mathcal{G}_{Na}(E_{Na} - V_{rest}) + \mathcal{G}_{Syn}(E_{Syn} - V_{rest}) + I_{th}.
\]

The circuit diagram corresponding to the above is shown in Figure 5. The random variable \( \delta \) corresponds to fluctuations in the membrane conductance due to synaptic and channel stochasticity and has a multiplicative effect on \( V \). On the other hand, \( I_n \) corresponds to an additive current noise.
source arising due to conductance fluctuations at $V_{\text{rest}}$. We assume that the conductance fluctuations about the $V_{\text{rest}}$ are zero-mean wide-sense-stationary (WSS) processes. Since the noise sources have different origins, it is also plausible to assume that they are statistically independent. Thus, $I_n$ is also a zero-mean WSS random process, $\langle I_n \rangle = 0$.

Our perturbative approximation implies that the statistical properties of the processes $\delta$ and $I_n$ are to be evaluated at $V = 0$. We are unable to solve equation 3.8 analytically because of the nonlinear (multiplicative) relationship between $\delta$ and $V$. However, since the membrane voltage does not change significantly, in most cases, the deviations of the conductances are small compared to the resting conductance of the cell,\(^4\) implying $\delta \ll 1$, which allows us to simplify equation 3.8 further to

$$\tau \frac{dV}{dt} + V = \frac{I_n}{G}. \quad (3.11)$$

This equation corresponds to a linear system driven by an additive noise source. It is straightforward to derive the statistical properties of $V$ in terms of the statistical properties of $I_n$. For instance, the power spectral density of $V(t)$, $S_V(f)$ can be written in terms of power spectral density of $I_n$, $S_{I_n}(f)$ as,

$$S_V(f) = \frac{S_{I_n}(f)}{G^2[1 + (2\pi f \tau)^2]^2}. \quad (3.12)$$

Since the noise sources are independent,

$$S_{I_n}(f) = S_{I_K}(f) + S_{I_{Na}}(f) + S_{ISyn}(f) + S_{I_{th}}(f). \quad (3.13)$$

\(^4\) The validity of this assumption can easily, and must, be verified on a case-by-case basis.
Figure 5: Equivalent electric circuit after linearization. Circuit diagram of the membrane patch containing different noise sources, close to equilibrium. The membrane voltage $V$ is measured as a deviation from the resting value $V_{\text{rest}}$. $G$ is the deterministic resting conductance of the patch, and $\tilde{g}$ is the random component due to the fluctuating conductances. The conductance fluctuations also give rise to an additive current noise source $I_n$.

Using the single Lorentzian approximations for the $K^+$ and $Na^+$ spectra, one can write an expression for the variance of the voltage noise as,

$$\sigma_V^2 \approx \frac{\pi}{G^2} \left[ \frac{S_{IK}(0)}{f_m + f_K} + \frac{S_{INa}(0)}{f_m + f_{Na}} \right] + \frac{S_{ISyn}(0)}{f_m + f_{Syn}} \frac{f_m^2 + f_{Syn}^2 f_m - 2f_{Syn}^2}{2(f_m^2 - f_{Syn}^2)} .$$  \hfill (3.14)

where $f_m = 1/2\pi \tau$ is the cutoff frequency corresponding to the membrane’s passive time constant.

3.1 Parameter Values. We consider a space-clamped cell body of a typical neocortical pyramidal cell as the substrate for our noisy membrane-
patch model. Estimates of the somatic/dendritic Na$^+$ conductance densities in neocortical pyramidal cells range from 4 to 12 mS/cm$^2$ (Huguenard, Hamill, & Prince, 1989; Stuart & Sakmann, 1994). We assume $\eta_{Na} = 2$ channels/µm$^2$ with $\gamma_{Na} = 20$ pS. K$^+$ channel densities are not known as reliably mainly because there are a multitude of different K$^+$ channel types.
However, some recent experimental and computational studies (Hoffman et al., 1997; Mainen & Sejnowski, 1998; Magee et al., 1998; Hoffman & Johnston, 1998) provide estimates for the $K^+$ densities in dendrites. We choose $n_K = 1.5 \text{ channels/}\mu\text{m}^2$, adopted from Mainen and Sejnowski (1998). The channel kinetics and the voltage dependence of the rate constants also correspond to Mainen, Joerges, Huguenard, and Sejnowski (1995). We use $R_m = 40,000 \Omega\text{cm}^2$ and $C_m = 1 \mu\text{F/cm}^2$ obtained from recent studies based on tight-seal whole cell recordings (Spruston, Jaffe, & Johnston, 1994; Major, Larkman, Jonas, Sakmann, & Jack, 1994), giving a passive time constant of $\tau_m = 40 \text{ msec}$. The entire soma is reduced to a single membrane patch of area $A = 1000 \mu\text{m}^2$.

The number of synapses at the soma is usually small, which leads us to $n_{Syn} = 0.01 \text{ synapses/}\mu\text{m}^2$, that is, 10 synapses. Other synaptic parameters are: $g_{\text{peak}} = 100 \text{ pS}$, $t_{\text{peak}} = 1.5 \text{ msec}$, $\lambda_n = 0.5 \text{ Hz}$. No account is made of synaptic transmission failure, but see Manwani and Koch (1998) for an analysis of synaptic unreliability and variability.

4 Results

We compute the current and voltage power spectra (shown in Figure 6) over the frequency range relevant for fast computations for the biophysical scenario discussed above. Experimentally, the current noise spectrum can be obtained by performing a voltage-clamp experiment, while the voltage noise spectra can be measured under current-clamp conditions. The voltage noise spectrum includes the effect of filtering (which has a Lorentzian power spectrum) due to the passive $RC$ circuit corresponding to the patch. In the article that follows, we show that in a real neuron, the cable properties of the system recorded from give rise to more complex behavior. Since we have modeled the membrane patch as a passive $RC$ filter and regarded the active voltage-gated ion channels as pure conductances, we obtained monotonic low-pass voltage spectra. In general, the small-signal membrane impedance due to voltage- and time-dependent conductances can exhibit resonance, giving rise to bandpass characteristics in the voltage noise spectra (Koch, 1984).

The relative magnitudes of the current noise power spectral densities ($S_{\text{i}(0)}$) and the amplitudes of voltage noise due to each noise source ($S_{\nu_i}$ and $\sigma_{\nu_i}$) are compared in Table 2.

The contribution of each noise source to the overall spectrum depends on the exact values of the parameters, including the channel kinetics, which can vary considerably across neuronal types and even from one neuronal location to another. For the parameter values we considered, thermal noise made the smallest contribution and is at the limit of what is experimentally resolvable using modern amplifiers. Background synaptic noise due to spontaneous activity was the dominant component of neuronal noise.
Table 2: Comparison of the Magnitudes of the Current Power Spectral Densities ($S_i(0)$, Units of $A^2/Hz$), Voltage Power Spectral Densities ($S_V(0)$, Units of $V^2/Hz$), and Voltage Standard Deviations ($\sigma_V$, Units of mV) of the Different Noise Sources in a Space-Clamped Somatic Membrane Patch.

<table>
<thead>
<tr>
<th>Noise Type</th>
<th>$S_i(0)$ ($A^2/Hz$)</th>
<th>$S_V(0)$ ($V^2/Hz$)</th>
<th>$\sigma_V$ (mV)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Thermal</td>
<td>$2.21 \times 10^{-30}$</td>
<td>$3.14 \times 10^{-31}$</td>
<td>$2.05 \times 10^{-2}$</td>
</tr>
<tr>
<td>K$^+$</td>
<td>$1.74 \times 10^{-27}$</td>
<td>$2.46 \times 10^{-8}$</td>
<td>$5.33 \times 10^{-1}$</td>
</tr>
<tr>
<td>Na$^+$</td>
<td>$1.67 \times 10^{-28}$</td>
<td>$2.36 \times 10^{-10}$</td>
<td>$5.59 \times 10^{-2}$</td>
</tr>
<tr>
<td>Synaptic</td>
<td>$4.12 \times 10^{-27}$</td>
<td>$5.84 \times 10^{-8}$</td>
<td>$8.54 \times 10^{-1}$</td>
</tr>
<tr>
<td>Total</td>
<td>$5.88 \times 10^{-27}$</td>
<td>$8.33 \times 10^{-8}$</td>
<td>$1.01$</td>
</tr>
</tbody>
</table>

The magnitude of noise for the scenario we consider here is small enough to justify the perturbative approximation, but it can be expected that for small structures, especially thin dendrites or spines, the perturbative approximation might be violated. However, treating a dendritic segment as a membrane patch is not an accurate model for real dendrites where currents can flow longitudinally. We shall address this problem again in the context of noise in linear cables in the following article.

There are numerous parameters in our analysis, and it would be extremely tedious to consider the combinatorial effect of varying them all. We restrict ourselves to studying the effect of varying a few biological relevant parameters.

4.1 Dependence on Area. Notice that varying the patch area $A$ does not affect the resting membrane potential $V_{rest}$ or the passive membrane time constant $r$. From equation 3.12, one can deduce the scaling behavior of $S_V$ with respect to $A$ in a straightforward manner. The current spectra in the numerator increase linearly with $A$ since the noise sources are in parallel, and independent their contributions add. However, since all the individual membrane conductances scale linearly with $A$, the total conductance $G$ also scales linearly with $A$. As a consequence, $S_V(f)$ and $\sigma_V^2$ scale inversely with $A$. Equivalently, $\sigma_V$ scales inversely as the square root of $A$.

This might appear counterintuitive since the number of channels increases linearly with $A$, but can be understood as follows. The current fluctuations are integrated by the RC filter corresponding to the membrane patch and manifest as voltage fluctuations. As the area of the patch increases, the variance of the current fluctuations increases linearly, but the input impedance decreases as well. Since the variance of the voltage fluctuations is proportional to the square of the impedance, the decrease in impedance more than offsets the linear increase due to the current and so the resulting voltage fluctuations are smaller. If all the channel and synaptic
densities are increased by the same factor (a global increase in the number of channels), an identical scaling behavior is obtained.

This suggests that the voltage noise from small patches might be large. Indeed, it is plausible to assume that for small neurons, the voltage fluctuations can be large enough to cause “spontaneous” action potentials. This phenomenon of noise-induced oscillations has indeed been observed in simulation studies (Skaugen & Wallace, 1979; Skaugen, 1980; Strassberg & DeFelice, 1993; Schneidman, Freedman, & Segev, 1998).

4.2 Dependence on Channel Densities. We first consider the effect of varying the different individual channel densities on the resting properties of the patch, that is, on $V_{\text{rest}}$, $G$, and $\tau$. The K$^+$ and Na$^+$ channel densities and the synaptic densities (except $g_L$) are first scaled individually and then together by the same factor. We denote the scale parameter by $\eta$. When all densities are scaled together, $\eta = 0$ corresponds to a purely passive patch containing leak channels alone, and $\eta = 1$ corresponds to the membrane patch scenario considered above (referred to as the nominal case). Similarly, when only the K$^+$ density is varied, $\eta = 0$ corresponds to a membrane patch without K$^+$ channels, and $\eta = 1$ denotes the nominal value. The results of this exercise are summarized in Figure 7A. Instead of using absolute values for the quantities of interest, we normalize them with respect to their nominal values corresponding to $\eta = 1$. Notice that when all the densities, except leak, are varied from $\eta = 0$ to $\eta = 2$, $V_{\text{rest}}$ varies (becomes more hyperpolarized) by less than 1%, and $\tau$ and $G^{-1}$ vary from about a 6% increase ($\eta = 0$) to a 5% decrease ($\eta = 2$). Despite the nonlinearities due to the active K$^+$ and Na$^+$ conductances, it is noteworthy that the quantities vary almost linearly with $\eta$, further justifying our perturbative approximation.

The effect of varying individual densities on $\sigma_V$ is explored in Figure 7B. In order to consider the contribution of a given process to the noise magnitude, we vary the associated density in a similar manner as above ($\eta$ goes from 0 to 2), while maintaining the others at their nominal values. We also compare the individual profiles to the case when all densities are scaled by the same factor. It is clear from the figure that the synaptic noise is the dominant noise source. The noise magnitude drops approximately from 1 mV to 0.5 mV in the absence of synaptic input (as $\eta$ varies goes from 1 to 0), but only to about 0.85 mV in the absence of K$^+$ channels. Varying the Na$^+$ density has a negligible effect on the noise magnitude. Similarly, the noise increases to 1.35 mV when the synaptic density is doubled ($\eta = 2$) with respect to its nominal values, but the increase to about 1.07 mV due to the doubling of K$^+$ density is much smaller.

5 Discussion

With this article, we initiate a systematic investigation of how various neuronal noise sources influence and ultimately limit the ability of one-
Figure 7: Influence of biophysical parameters. (A) Dependence of the passive membrane parameters ($V_{\text{rest}}, \tau$) on the channel and synaptic densities. The $K^+$ and $Na^+$ channel densities and the synaptic density are scaled by the same factor $\eta$ that varies from $\eta = 0$ (corresponding to a completely passive system) to $\eta = 2$. $\eta = 1$ corresponds to the nominal parameter values used to generate Figure 6. The membrane parameters (denoted generically by $k$) are expressed as a ratio of their nominal values at $\eta = 1$ (denoted by $k_0$). (B) Effect of varying individual densities (the remaining densities are maintained at their nominal values) on the magnitude of the voltage noise $\sigma_V$.

dimensional cable structures to propagate information. Ultimately we are interested in answering such questions as whether the length of the apical dendrite of a neocortical pyramidal cell is limited by considerations of signal-to-noise, what influences the noise level in the dendritic tree of some neuron endowed with voltage-dependent channels, how accurately
the time course of a synaptic signal can be reconstructed from the voltage at
the spike initiation zone, what the channel capacity of an unreliable synapse
onto a spine is, and so on. Our research program is driven by the hypoth-
thesis that noise fundamentally limits the precision, speed, and accuracy of
computation in the nervous system (Koch, 1999).

Providing satisfactory answers to these issues requires the characteri-
zation of the various neuronal noise sources that can cause loss of signal
fidelity at different stages in the neuronal link. This is what we have un-
dertaken in this article. The analysis of membrane noise has a long and
successful history. Before the patch-clamp technique was developed, mem-
brane noise analysis was traditionally used to provide indirect evidence
for the existence of ionic channels and obtain estimates of their biophysical
properties. This has been admirably described in DeFelice (1981). Despite the
universality of patch-clamp methods to study single channels today, noise
analysis remains a useful tool for certain problems (Traynelis & Jaramillo,
1998).

In the approaches mentioned above, noise analysis has been exploited as
an investigative measurement technique. Our interest lies in understanding
how the inherent sources of noise at the single-neuron level have bearing
on the temporal precision with which neurons respond to sensory input or
direct current injection. These questions are receiving renewed scrutiny. It
is becoming increasingly apparent how a transition from discrete, micro-
scopic, and stochastic channels is made to continuous, macroscopic, and
deterministic currents (Strassberg & DeFelice, 1993). Several attempts have
also been made to explore whether the rich dynamics of neuronal activity
and the temporal reliability of neural spike trains can be explained in terms
of microscopic fluctuations (Clay & DeFelice, 1983; DeFelice & Isaac, 1992;
White, Budde, & Kay, 1995; Chow & White, 1996; Schneidman et al., 1998).
This article reflects a continuation of this pursuit.

The key result of our approach is that we are able to derive closed-form
expressions for the membrane voltage fluctuations due to the three dom-
inant noise types in neuronal preparations: thermal, channel, and synap-
tic noise. However, we obtain these results at a price. We assume that the
deviations of the membrane potential about its resting value, as a result
of “spontaneous” synaptic input and channels switching, are small. This
allows us to make a perturbative approximation and express conductance
changes as small deviations around their resting values, allowing us to treat
them as sources of current noise. The validity of this supposition needs to
be carefully evaluated empirically. This can be considered analogous to the
linearization of nonlinear differential equations about a quiescent point, the
only difference being that the quantities being dealt with are stochastic. (For
a related approach, see Larsson, Kleene, & Lecar, 1997).

This approximation enables us to write down a stochastic differential
equation (equation 3.8) governing the dynamics of voltage fluctuations.
Since we are unable to solve equation 3.8 analytically, we invoke another
simplifying assumption: that the conductance fluctuations are small compared to the total resting conductance. The validity of this assumption can also be easily verified. This assumption simplifies equation 3.8 into a linear stochastic differential equation that is straightforward to analyze.

Using this approach, all three noise sources can be regarded as additive, and we can solve the associated linear stochastic membrane equation and obtain expressions for the spectra and variance of the voltage fluctuations in closed form. We show in the companion article that we can also apply a similar calculus when the noise sources are distributed in complex one-dimensional neuronal cable structures. This allows us to estimate the information transmission properties of linear cables under a signal detection and a signal reconstruction framework. We have reported elsewhere how these two paradigms can be exploited to characterize the capacity of simple model of an unreliable and noisy synapse (Manwani & Koch, 1998). The validity of these theoretical results needs to be assessed by comparison with experimental data from a well-characterized neurobiological system. We are currently engaged in such a quantitative comparison involving neocortical pyramidal cells (Manwani et al., 1998).

### Appendix: List of Symbols

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Description</th>
<th>Dimension</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\gamma_K$</td>
<td>Single potassium channel conductance</td>
<td>pS</td>
</tr>
<tr>
<td>$\gamma_{Na}$</td>
<td>Single sodium channel conductance</td>
<td>pS</td>
</tr>
<tr>
<td>$\gamma_L$</td>
<td>Single leak channel conductance</td>
<td>pS</td>
</tr>
<tr>
<td>$\eta_K$</td>
<td>Potassium channel density</td>
<td>channels/$\mu m^2$ (patch) channels/$\mu m$ (cable)</td>
</tr>
<tr>
<td>$\eta_{Na}$</td>
<td>Sodium channel density</td>
<td>channels/$\mu m^2$ (patch) channels/$\mu m$ (cable)</td>
</tr>
<tr>
<td>$\eta_{Syn}$</td>
<td>Synaptic density</td>
<td>synapses/$\mu m^2$ (patch) synapses/$\mu m$ (cable)</td>
</tr>
<tr>
<td>$\lambda$</td>
<td>Steady-state electronic space constant</td>
<td>$\mu m$</td>
</tr>
<tr>
<td>$\lambda_n$</td>
<td>Spontaneous background activity</td>
<td>Hz</td>
</tr>
<tr>
<td>Symbol</td>
<td>Description</td>
<td>Unit</td>
</tr>
<tr>
<td>--------</td>
<td>------------------------------------------------------------------------------</td>
<td>------</td>
</tr>
<tr>
<td>$\sigma_s$</td>
<td>Standard deviation of injected current</td>
<td>pA</td>
</tr>
<tr>
<td>$\sigma_V$</td>
<td>Standard deviation of voltage noise</td>
<td>mV</td>
</tr>
<tr>
<td>$\theta_i$</td>
<td>Time constant of sodium inactivation</td>
<td>msec</td>
</tr>
<tr>
<td>$\theta_a$</td>
<td>Time constant of sodium activation</td>
<td>msec</td>
</tr>
<tr>
<td>$\theta_k$</td>
<td>Time constant of potassium activation</td>
<td>msec</td>
</tr>
<tr>
<td>$\tau, \tau_m$</td>
<td>Membrane time constant</td>
<td>msec</td>
</tr>
<tr>
<td>$\xi$</td>
<td>Normalized coding fraction</td>
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</tr>
<tr>
<td>$A$</td>
<td>Patch area</td>
<td>$\mu$m$^2$</td>
</tr>
<tr>
<td>$B_s$</td>
<td>Bandwidth of injected current</td>
<td>Hz</td>
</tr>
<tr>
<td>$c_m$</td>
<td>Specific membrane conductance per unit length</td>
<td>F/$\mu$m</td>
</tr>
<tr>
<td>$C$</td>
<td>Total membrane capacitance</td>
<td>F</td>
</tr>
<tr>
<td>$C_m$</td>
<td>Specific membrane capacitance</td>
<td>$\mu$F/$\mu$m$^2$</td>
</tr>
<tr>
<td>$C_{iK}$</td>
<td>Autocorrelation of potassium current noise</td>
<td>$A^2/\mu$m$^2$ (patch)</td>
</tr>
<tr>
<td>$C_{iNa}$</td>
<td>Autocorrelation of sodium current noise</td>
<td>$A^2/\mu$m$^2$ (patch)</td>
</tr>
<tr>
<td>$C_{iSyn}$</td>
<td>Autocorrelation of synaptic current noise</td>
<td>$A^2/\mu$m$^2$ (patch)</td>
</tr>
<tr>
<td>$d$</td>
<td>Cable diameter</td>
<td>$\mu$m</td>
</tr>
<tr>
<td>$E_K$</td>
<td>Potassium reversal potential</td>
<td>mV</td>
</tr>
<tr>
<td>$E_{Na}$</td>
<td>Sodium reversal potential</td>
<td>mV</td>
</tr>
<tr>
<td>$E_L$</td>
<td>Leak reversal potential</td>
<td>mV</td>
</tr>
<tr>
<td>$E_{Syn}$</td>
<td>Synaptic reversal potential</td>
<td>mV</td>
</tr>
<tr>
<td>$g_K$</td>
<td>Potassium conductance</td>
<td>S</td>
</tr>
<tr>
<td>$g_L$</td>
<td>Leak conductance</td>
<td>S</td>
</tr>
<tr>
<td>$g_{peak}$</td>
<td>Peak synaptic conductance change</td>
<td>pS</td>
</tr>
<tr>
<td>$g_{Na}$</td>
<td>Sodium conductance</td>
<td>S</td>
</tr>
<tr>
<td>Symbol</td>
<td>Description</td>
<td></td>
</tr>
<tr>
<td>--------</td>
<td>-------------</td>
<td></td>
</tr>
<tr>
<td>( g_{syn} )</td>
<td>Synaptic conductance</td>
<td></td>
</tr>
<tr>
<td>( G )</td>
<td>Total membrane conductance</td>
<td></td>
</tr>
<tr>
<td>( h_\infty )</td>
<td>Steady-state sodium inactivation</td>
<td></td>
</tr>
<tr>
<td>( I(S; D) )</td>
<td>Mutual information for signal detection</td>
<td></td>
</tr>
<tr>
<td>( I(I_s, V) )</td>
<td>Information rate for signal estimation</td>
<td></td>
</tr>
<tr>
<td>( m_\infty )</td>
<td>Steady-state sodium activation</td>
<td></td>
</tr>
<tr>
<td>( n_\infty )</td>
<td>Steady-state potassium inactivation</td>
<td></td>
</tr>
<tr>
<td>( N_{syn} )</td>
<td>Number of synapses activated by a presynaptic spike</td>
<td></td>
</tr>
<tr>
<td>( P_e )</td>
<td>Probability of error in signal detection</td>
<td></td>
</tr>
<tr>
<td>( r_a )</td>
<td>Intracellular resistance per unit length</td>
<td></td>
</tr>
<tr>
<td>( R_l )</td>
<td>Intracellular resistivity</td>
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</tr>
<tr>
<td>( R_m )</td>
<td>Specific leak or membrane resistance</td>
<td></td>
</tr>
<tr>
<td>( S_{IK} )</td>
<td>Power spectral density of potassium current noise</td>
<td></td>
</tr>
<tr>
<td>( S_{INa} )</td>
<td>Power spectral density of sodium current noise</td>
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</tr>
<tr>
<td>( S_{ISyn} )</td>
<td>Power spectral density of synaptic current noise</td>
<td></td>
</tr>
<tr>
<td>( S_{ITh} )</td>
<td>Power spectral density of thermal current noise</td>
<td></td>
</tr>
<tr>
<td>( S_V )</td>
<td>Power spectral density of membrane voltage noise</td>
<td></td>
</tr>
<tr>
<td>( t )</td>
<td>Time</td>
<td></td>
</tr>
<tr>
<td>( t_{peak} )</td>
<td>Time-to-peak for synaptic conductance</td>
<td></td>
</tr>
<tr>
<td>( T )</td>
<td>Normalized time ((t/\tau))</td>
<td></td>
</tr>
<tr>
<td>( V )</td>
<td>Membrane potential relative to ( V_{rest} )</td>
<td></td>
</tr>
</tbody>
</table>
\begin{align*}
V_m & \text{ Membrane potential} \quad \text{mV} \\
V_{rest} & \text{ Resting potential} \quad \text{mV} \\
x, y & \text{ Position} \quad \text{µm} \\
X & \text{ Normalized distance } (x/\lambda) \quad 1
\end{align*}

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